

Reg No.: _____

Name: _____

APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY

B.Tech Degree S8 (R,S) Exam April 2025 (2019 Scheme)

Course Code: ECT446**Course Name: MICROWAVE DEVICES AND CIRCUITS****Max. Marks: 100****Duration: 3 Hours****PART A***Answer all questions, each carries 3 marks.*

Marks

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|----|---|-----|
| 1 | Explain the important features of microwaves? | (3) |
| 2 | List the key properties of the IMPATT diode and its areas of application. | (3) |
| 3 | Discuss the biasing methods in Bipolar transistor? | (3) |
| 4 | Describe One port negative resistance oscillators. | (3) |
| 5 | Explain the significance of impedance matching. | (3) |
| 6 | Write notes on Quarter wave transformer. | (3) |
| 7 | Explain the importance of $k-\beta$ diagram in microwave filters. | (3) |
| 8 | Explain the significance of Kuroda's identity in filter implementation | (3) |
| 9 | Compare Hybrid MIC & Monolithic MIC . | (3) |
| 10 | Write notes on Diode phase shifter. | (3) |

PART B**Answer any one full question from each module, each carries 14 marks.****Module I**

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|----|---|------|
| 11 | a) Explain four modes of oscillation in Gunn diode. | (14) |
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OR

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| 12 | a) Explain Ridley–Watkins–Hilsum theory with the help of two valley model. | (8) |
| | b) A TRAPATT diode has the following parameters | (6) |
| | Doping concentration $N_A = 2 \times 10^{15} \text{cm}^{-3}$ | |
| | Current density: $J = 20 \text{kA/cm}^2$. | |
| | Calculate the avalanche-zone velocity. | |

Module II

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| 13 | a) Explain the structure and working of MESFET. | (7) |
| | b) Derive the expression for power gain of microwave amplifier. | (7) |

OR

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|----|---|------|
| 14 | a) Derive the expression for matched gain $G_{T_{\max}}$ and maximum stable gain G_{msg} | (14) |
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in Single-Stage transistor amplifier design.

Module III

- 15 a) Show that when two two-port networks are connected in cascade, the overall ABCD matrix is obtained by multiplying the ABCD matrices of each individual network. (8)
- b) Explain the properties of Scattering Matrix? (6)

OR

- 16 a) Explain matching with lumped elements. (7)
- b) Explain the TRL technique in Signal flow graph with neat diagrams (7)

Module IV

- 17 a) Explain periodic structures in Microwave filters. (6)
- b) Explain m-derived section of Image parameter method in filter design. (8)

OR

- 18 a) Explain filter design by insertion loss method. (10)
- b) Explain Richard's transformation in filter implementation. (4)

Module V

- 19 a) Explain the structure of Microstrip planar transmission line with neat diagram. (8)
- b) Explain lumped elements of integrated circuits. (6)

OR

- 20 a) Explain microwave resonators? (4)
- b) Write short notes on : i) Discontinuities ii) Isolator (10)
